HD74HC259

8-bit Addressable Latch

HITACHI

Description

The HD74HC259 has a single data input (D), 8 latch outputs (Q_0-Q_7), 3 address inputs (A, B, and C), a common enable input (E), and a common clear input. To operate this device as an addressable latch, data is held on the D input, and the address of the latch into which the data is to be entered is held on the A, B and C inputs. When enable is taken low the data flows through to the addressed output. The data is stored when enable transitions from low to high. All unaddressed latches will remain unaffected. With enable in the high state the device is deselected, and all latches remain in their previous state, unaffected by changes on the data or address inputs. To eliminate the possibility of entering erroneous data into the latches, the enable should be held high (inactive) while the address lines are changing.

If enable is held high and clear is taken low all eight latches are cleared to a low state. If enable is low all latches except the addressed latch will be cleared. The addressed latch will instead follow the D input, effectively implementing a 3-to-8 line decoder.

Features

- High Speed Operation: t_{pd} (Data to Output) = 16 ns typ (C_L = 50 pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: V_{CC} = 2 to 6 V
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 µA max (Ta = 25°C)

Function Table

Inputs				
Clear	**G**	**Output of Addressed Latch**	**Each Other Output**	**Function**
H	L	D	Qio	Addressable latch
H	H	Qio	Qio	Memory
L	L	D	L	8-line demultiplexer
L	H	L	L	Clear

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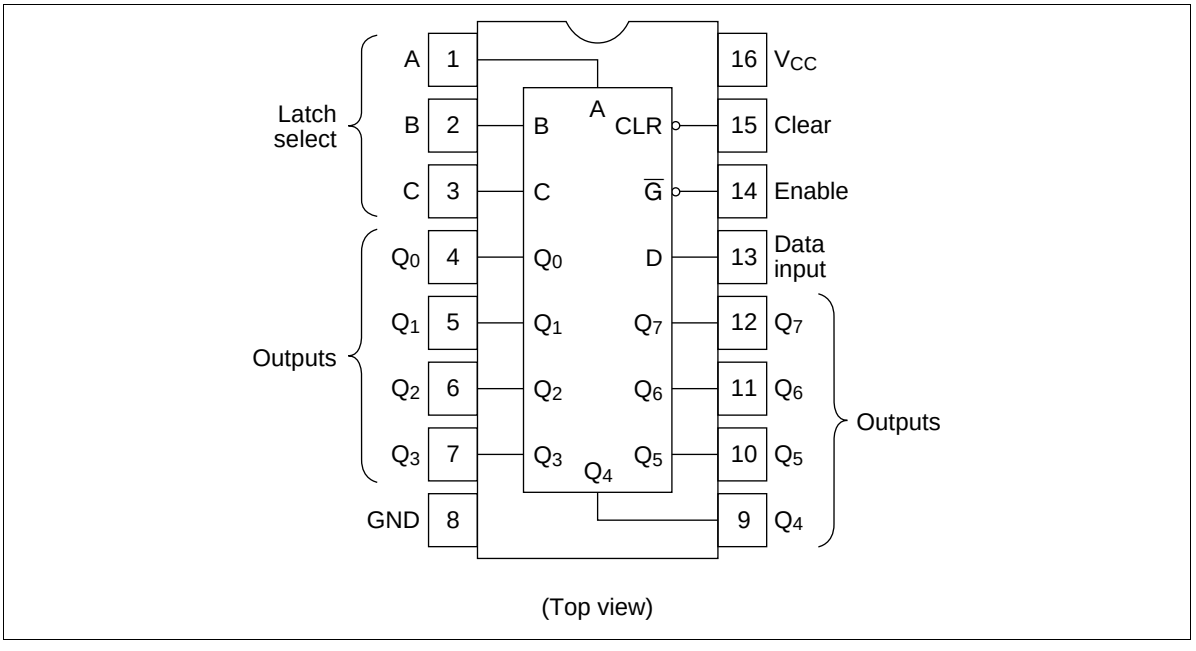
Select Inputs

C	B	A	Latch Addressed
L	L	L	0
L	L	H	1
L	H	L	2
L	H	H	3
H	L	L	4
H	L	H	5
H	H	L	6
H	H	H	7

Notes: 1. D: the level at the data input

2. Qio: the level of Qi (i = 0, 1, ⋯7, as apropriate) before the indicated steady-state input conditions were established.

Pin Arrangement



(Top view)

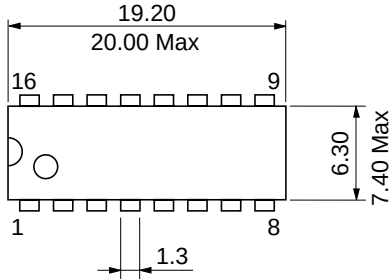
DC Characteristics

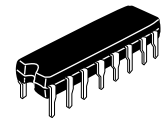
Item	Symbol	V_{CC} (V)	Ta = 25°C Min	Typ	Max	Ta = –40 to +85°C Min	Max	Unit	Test Conditions	
Input voltage	V_{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V_{IL}	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V_{OH}	2.0	1.9	2.0	—	1.9	—	V	Vin = V_{IH} or V_{IL}	I_{OH} = –20 µA
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	—	—	4.13	—			I_{OH} = –4 mA
		6.0	5.68	—	—	5.63	—			I_{OH} = –5.2 mA
	V_{OL}	2.0	—	0.0	0.1	—	0.1	V	Vin = V_{IH} or V_{IL}	I_{OL} = 20 µA
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			I_{OL} = 4 mA
		6.0	—	—	0.26	—	0.33			I_{OL} = 5.2 mA
Input current	Iin	6.0	—	—	±0.1	—	±1.0	µA	Vin = V_{CC} or GND	
Quiescent supply current	I_{CC}	6.0	—	—	4.0	—	40	µA	Vin = V_{CC} or GND, Iout = 0 µA	

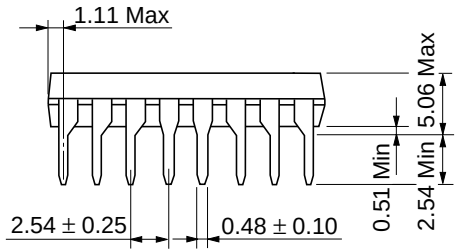
AC Characteristics (C_L = 50 pF, Input $t_r = t_f$ = 6 ns)

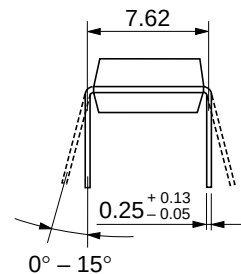
			Ta = 25°C			Ta = –40 to +85°C			
Item	**Symbol**	**V_{cc} (V)**	**Min**	**Typ**	**Max**	**Min**	**Max**	**Unit**	**Test Conditions**
Propagation delay time	t_{PHL}	2.0	—	—	185	—	230	ns	Data to output
	t_{PLH}	4.5	—	16	37	—	46		
		6.0	—	—	31	—	39		
		2.0	—	—	215	—	270		Latch select to output
		4.5	—	20	43	—	54		
		6.0	—	—	37	—	46		
		2.0	—	—	200	—	250		Enable to output
		4.5	—	17	40	—	50		
		6.0	—	—	34	—	43		
	t_{PHL}	2.0	—	—	155	—	195	ns	Clear to output
		4.5	—	15	31	—	39		
		6.0	—	—	26	—	33		
Pulse width	t_w	2.0	80	—	—	100	—	ns	Clear, Enable
		4.5	16	6	—	20	—		
		6.0	14	—	—	17	—		
Setup time	t_{su}	2.0	100	—	—	125	—	ns	Latch select or data to enable
		4.5	20	5	—	25	—		
		6.0	17	—	—	21	—		
Hold time	t_h	2.0	5	—	—	5	—	ns	Latch select or data to enable
		4.5	5	–1	—	5	—		
		6.0	5	—	—	5	—		
Output rise/fall time	t_{TLH}	2.0	—	—	75	—	95	ns	
	t_{THL}	4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
Input capacitance	Cin	—	—	5	10	—	10	pF	

Unit: mm



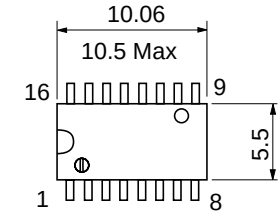


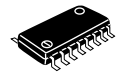


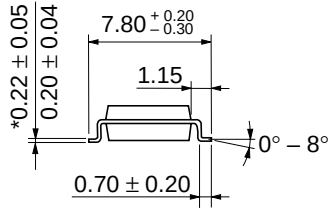


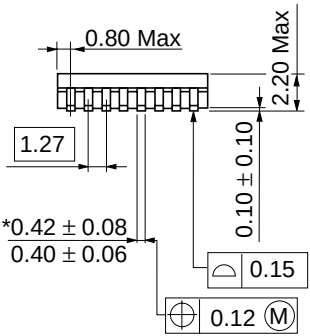
Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

Unit: mm





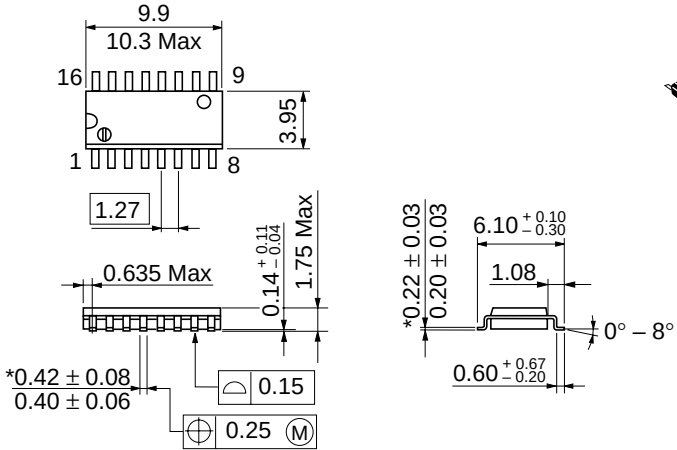




*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.24 g

Unit: mm



Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

*Dimension including the plating thickness
Base material dimension

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